

www.din-tek.jp

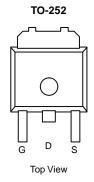
P-Channel 20 V (D-S) MOSFET

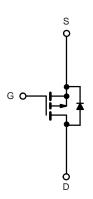
PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A) ^a			
- 20	0.007 at $V_{GS} = -4.5 \text{ V}$	- 60			
- 20	0.009 at V _{GS} = - 2.5 V	- 53			

FEATURES

- DT-Trench Power MOSFET 100 % R_g Tested 100 % UIS Tested







P-Channel MOSFET

ABSOLUTE MAXIMUM RAT	INGS (T _C = 25 °C, unless other	rwise noted)			
Parameter	Symbol	Limit ± 12	Unit V		
Gate-Source Voltage	V_{GS}				
Continuous Brain Comment (T. 475 °C)	T _C = 25 °C		- 60 ^a	^	
Continuous Drain Current (T _J = 175 °C)	T _C = 125 °C	ID	- 45		
Pulsed Drain Current	I _{DM}	- 220	Α		
Avalanche Current	I _{AR}	- 60			
Repetitive Avalanche Energy ^b	L = 0.1 mH	E _{AR}	130	mJ	
Power Dissipation	T _C = 25 °C (TO-220AB and TO-263)	В	127 ^d	W	
rower Dissipation	T _A = 25 °C (TO-263) ^c	P_{D}	3.15		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Limit	Unit			
Junction-to-Ambient	PCB Mount (TO-263) ^c	- R _{thJA}	35	°C/W		
Sunction-to-Ambient	Free Air (TO-220AB)		55			
Junction-to-Case		R _{thJC}	0.8			

Notes:

- a. Package limited.
- b. Duty cycle \leq 1 %.
- c. When mounted on 1" square PCB (FR-4 material).
- d. See SOA curve for voltage derating.

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply.



DTU60P02 www.din-tek.jp

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_{D} = -250 \mu\text{A}$	- 20			V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$	- 0.5		- 2.5	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
		V _{DS} = - 30 V, V _{GS} = 0 V			- 1	μА	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 16 V, V _{GS} = 0 V, T _J = 125 °C			- 50		
		V _{DS} = - 16 V, V _{GS} = 0 V, T _J = 175 °C			- 250		
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 10 V	- 60			Α	
		$V_{GS} = -4.5 \text{ V}, I_D = -30 \text{ A}$		0.007	0.0085	Ω	
Drain-Source On-State Resistance ^a	D	V _{GS} = - 4.5 V, I _D = - 30 A, T _J = 125 °C			0.010		
Diam-Source On-State Resistance	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -30 \text{ A}, T_J = 175 \text{ °C}$			0.013		
		$V_{GS} = -2.5 \text{ V}, I_D = -20 \text{ A}$		0.009	0.0125		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 16 V, I _D = - 30 A	20			S	
Dynamic ^b							
Input Capacitance	C _{iss}			8400		pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 \text{ V}, V_{DS} = -25 \text{ V}, f = 1 \text{ MHz}$		1505			
Reversen Transfer Capacitance	C _{rss}			710			
Total Gate Charge ^c	Qg			160	240	nC	
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = -15 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -30 \text{ A}$		32			
Gate-Drain Charge ^c	Q _{gd}]		30			
Turn-On Delay Time ^c	t _{d(on)}			27			
Rise Time ^c	t _r	$V_{DD} = -15 \text{ V}, R_{L} = 0.2 \Omega$		220		ns	
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong -30 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_g = 2.5 \Omega$		140			
Fall Time ^c	t _f]		215		1	
Source-Drain Diode Ratings and Cha	racteristics ^b	(T _C = 25 °C)					
Continuous Current	I _S				- 60	۸	
Pulsed Current	I _{SM}				- 220	Α	
Forward Voltage ^a	V _{SD}	I _F = - 30 A, V _{GS} = 0 V		- 0.8	- 1.2	V	
Reverse Recovery Time	t _{rr}			55	100	ns	
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = - 30 A, dI/dt = 100 A/μs		2.5	5	Α	
Reverse Recovery Charge	Q _{rr}			0.07	0.25	μC	

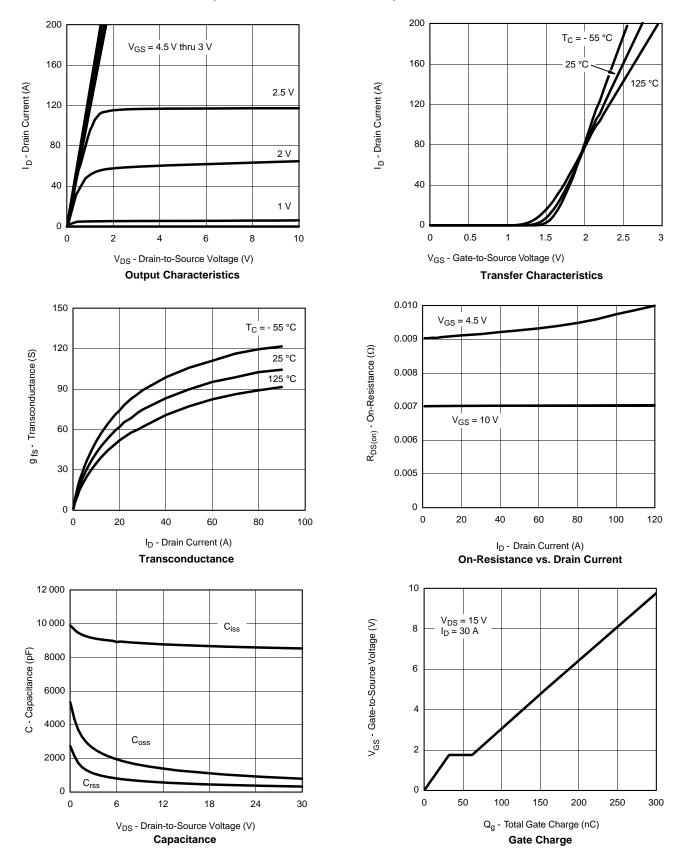
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

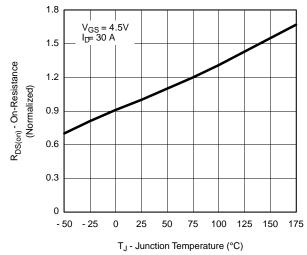


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

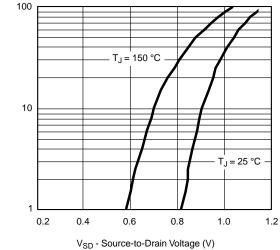




TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

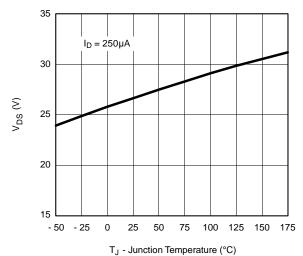


On-Resistance vs. Junction Temperature

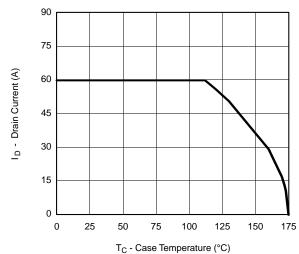


I_S - Source Current (A)

Source-Drain Diode Forward Voltage



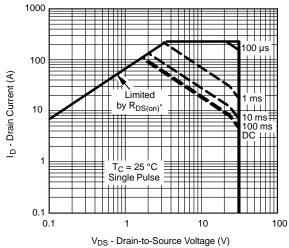
Drain Source Breakdown vs. Junction Temperature



Maximum Avalanche and Drain Current vs. Case Temperature

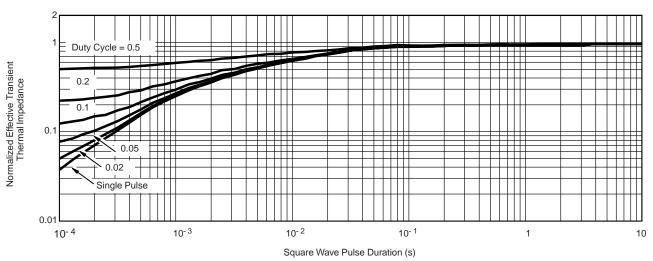


THERMAL RATINGS



* V_{GS} > minimum V_{GS} at which R_{DS(on)} is specified

Safe Operating Area

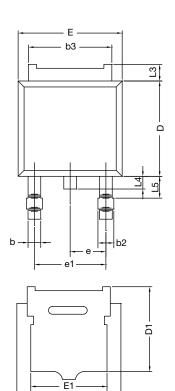


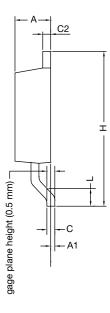
Normalized Thermal Transient Impedance, Junction-to-Case





TO-252AA CASE OUTLINE





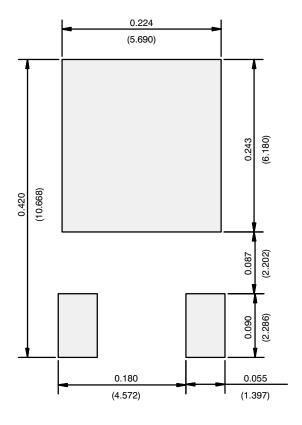
	MILLIN	METERS	INCHES			
DIM.	MIN.	MAX.	MIN.	MAX.		
Α	2.18	2.38	0.086	0.094		
A1	-	0.127	-	0.005		
b	0.64	0.88	0.025	0.035		
b2	0.76	1.14	0.030	0.045		
b3	4.95	5.46	0.195	0.215		
С	0.46	0.61	0.018	0.024		
C2	0.46	0.89	0.018	0.035		
D	5.97	6.22	0.235	0.245		
D1	5.21	-	0.205	-		
Е	6.35	6.73	0.250	0.265		
E1	4.32	-	0.170	-		
Н	9.40	10.41	0.370	0.410		
е	2.28	BSC	0.090 BSC			
e1	4.56	BSC 0.180 BSC		4.56 BSC		BSC
L	1.40	1.78	0.055	0.070		
L3	0.89	1.27	0.035	0.050		
L4	-	1.02	-	0.040		
L5	1.14	1.52	0.045	0.060		
ECN: X12-0247-Rev. M, 24-Dec-12						

DWG: 5347 Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

www.din-tek.jp

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Din-Tek Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Din-Tek"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Din-Tek makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Din-Tek disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Din-Tek's knowledge of typical requirements that are often placed on Din-Tek products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Din-Tek's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Din-Tek products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Din-Tek product could result in personal injury or death. Customers using or selling Din-Tek products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Din-Tek personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Din-Tek. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Din-Tek Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Din-Tek documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Din-Tek Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Din-Tek documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.